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TO: Commissioner for Patents

FROM:

George H. Gates

Attn: Examiner Loke, Steven Ho Yin

OUR REF.:

G&C 30794.94-US-WO

Patent Examining Corps

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Total pages, including cover letter: 6

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Title of Document Transmitted:	TRANSMITTALS, INFORMATION DISCLOSURE STATEMENT (37 C.F.R. §1.97(B)) AND FORM 1449
Applicant:	Benjamin A. Haskell et al.
Serial No.:	10/537,385
Filed:	June 3, 2005
Group Art Unit:	2811
Title:	GROWTH OF PLANAR, NON-POLAR A-PLANE GALLIUM NITRIDE BY HYDRIDE VAPOR PHASE EPITAXY
Our Ref. No.:	G&C 30794.94-US-WO

Please charge all fees to Deposit Account No. 50-0494 of Gates & Cooper LLP.

Name: George H. Gates

Reg. No.: 33,500

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Signature

January 15, 2007

Date

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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FROM-Gates & Cooper LLP

Examiner:

Loke, Steven Ho Yin

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CERTIFICATE OF MAILING OR TRANSMISSION UNDER 37 CFR 1.8

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Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

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Transmittal sheet, in duplicate, containing a Certificate of Mailing or Transmission under 37 CFR 1.8.

Information Disclosure Statement and Form PTO-1449.

Please consider this a PETITION FOR EXTENSION OF TIME for a sufficient number of months to enter these papers, if appropriate.

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Customer Number 22462

GATES & COOPER LLP

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Name: George H. Gates

INFORMATION DISCLOSURE STATEMENT (37 C.F.R. §1.97(b))

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

With regard to the above-identified application, the items of information listed on the enclosed Form 1449 are brought to the attention of the Examiner.

This statement should be considered because it is submitted before the mailing date of a first Office Action on-the-ments. Accordingly, no fee is due for consideration of the items listed on the enclosed Form 1449.

In accordance with 37 C.F.R. §1.98(a)(2), a copy of each foreign parent document and each non-patent document listed on the enclosed Form 1449 is provided.

No representation is made that a reference is "prior art" within the meaning of 35 U.S.C. §§ 102 and 103 and Applicants reserve the right, pursuant to 37 C.F.R. § 1.131 or otherwise, to establish that the reference(s) are not "prior art". Moreover, Applicants do not represent that a reference has been thoroughly reviewed or that any relevance of any portion of a reference is intended.

G&C 30794,94-US-WO

Consideration of the items listed is respectfully requested. Pursuant to the provisions of M.P.E.P. 609, it is requested that the Examiner return a copy of the attached Form 1449, marked as being considered and initialed by the Examiner, to the undersigned with the next official communication.

Please direct any response or inquiry to the below-signed attorney at (310) 641-8797.

Respectfully submitted,

GATES & COOPER LLP Attorneys for Applicant(s)

Howard Hughes Center 6701 Center Drive West, Suite 1050 Los Angeles, California 90045 (310) 641-8797

Date: January 15, 2007

GHG/cf

George H. Gates Reg. No.: 33,500

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T-590 P.006/006 F-073

Date Mailed: January 15, 2007

Sheet 1 of 1

Form 1449*	Docket Number: G&C 30794.94-US-WC	Application Number: 10/537,385	CEIVED
INFORMATION DISCLOSURE STATEMENT	Applicant: Benjamin A. Haskell et al.	Cours A - Unic 2011	AL FAX CENTE
IN AN APPLICATION	Filing Date: June 3, 2005	Group Art Unic 2811	LO DEM ! E

JAN 1 5 2007 U.S. PATENT DOCUMENTS FILING DATE IF CLASS SUBCLASS EXAMINER DOCUMENT NO. DATE NAME **APPROPRLATE** INITIAI. 08/27/2002 Vaudo et al. 6,440,823 6,627,551 09-30-2003 Nishio Johji et al. FOREIGN PATENTS TRANSLATION SUBCLASS CLASS DOCUMENT NO. DATE COUNTRY 10/30/2003 WO 03/089694A 01/28/2004 EP 1 385 196 A ŢΡ 2001342100 A 11-12-2001 NON-PATENT DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.) GUS et al: "The Impact of initial growth and substrate nitridation on thick GaN growth on sapphire by hidride vapor phase epiraxy", Journal of Crystal Growth, North-Holland Publishing, Amsterdam, NL, vol. 231, no. 3, October 2001 (2001-10), pages 342-351

EXAMINER:	DATE CONSIDERED:				
	I the morn con 1 I' the selection if one in				
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in					
conformance and not considered. Include copy of this form for next communication to the Applicant.					
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^{*}Substitute Disclosure Statement Form (PTO-1449)